

# **Device Modeling Report**

COMPONENTS:  
DIODE/ SCHOTTKY RECTIFIER / STANDARD  
PART NUMBER: CMS08  
MANUFACTURER: TOSHIBA

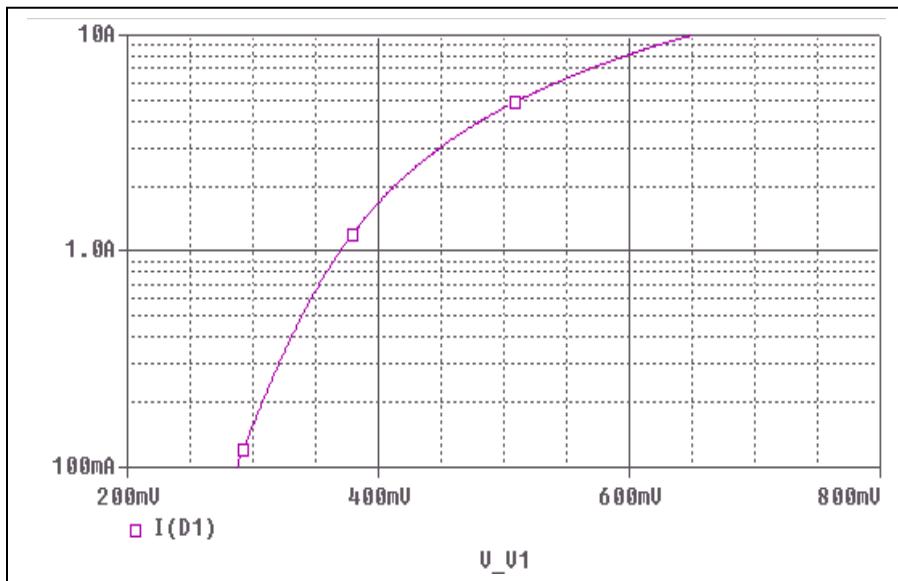


**Bee Technologies Inc.**

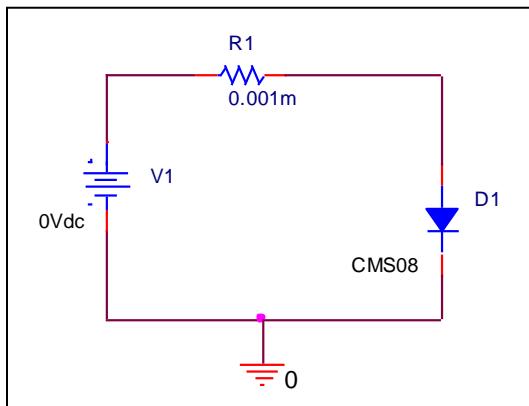
PSpice model parameter	Model description
IS	Saturation Current
N	Emission Coefficient
RS	Series Resistance
IKF	High-injection Knee Current
CJO	Zero-bias Junction Capacitance
M	Junction Grading Coefficient
VJ	Junction Potential
ISR	Recombination Current Saturation Value
BV	Reverse Breakdown Voltage(a positive value)
IBV	Reverse Breakdown Current(a positive value)
TT	Transit Time
EG	Energy-band Gap

## Forward Current Characteristic

Circuit Simulation Result

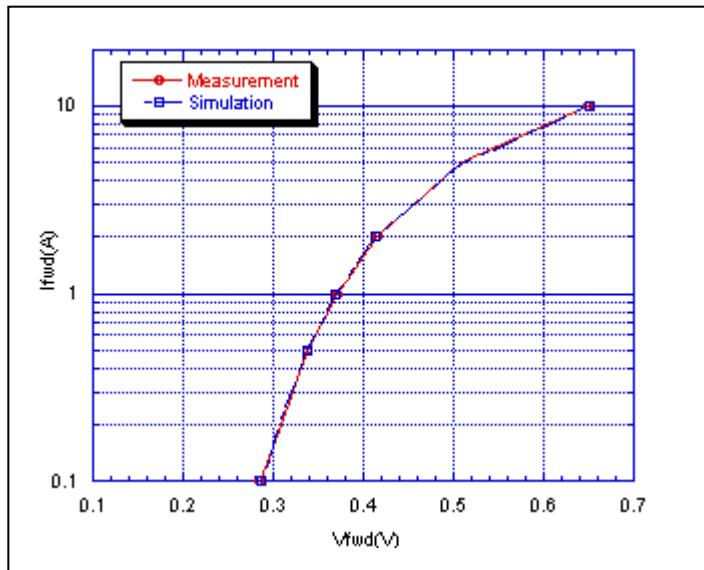


Evaluation Circuit



## Comparison Graph

Circuit Simulation Result

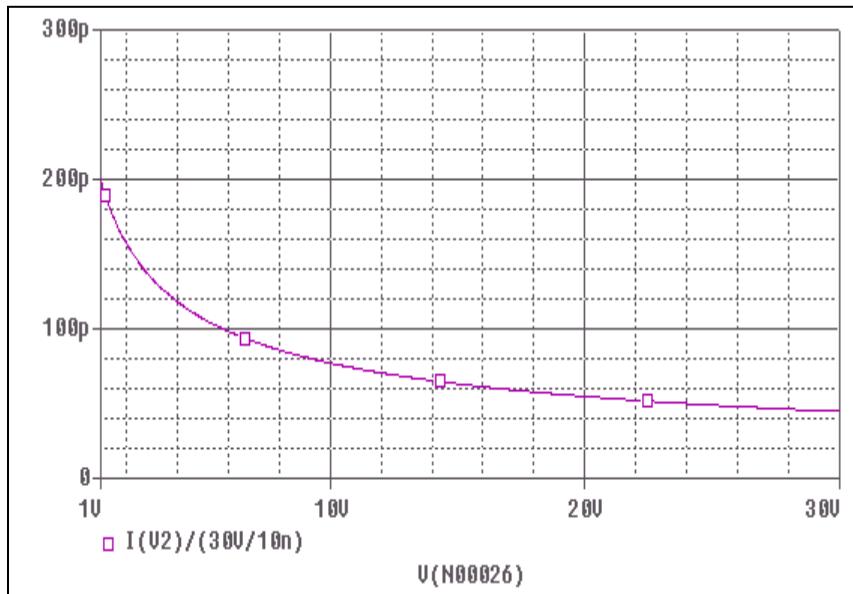


Simulation Result

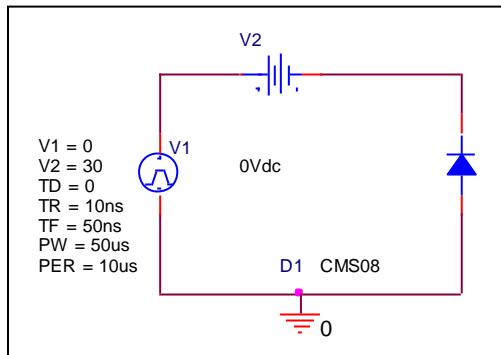
$I_{fwd}$ (A)	$V_{fwd}$ (V) Measurement	$V_{fwd}$ (V) Simulation	%Error
0.1	0.285	0.287	0.60
0.2	0.308	0.307	-0.26
0.5	0.338	0.339	0.21
1	0.370	0.369	-0.19
2	0.415	0.413	-0.55
5	0.510	0.511	0.27
10	0.650	0.651	0.09

## Junction Capacitance Characteristic

Circuit Simulation Result

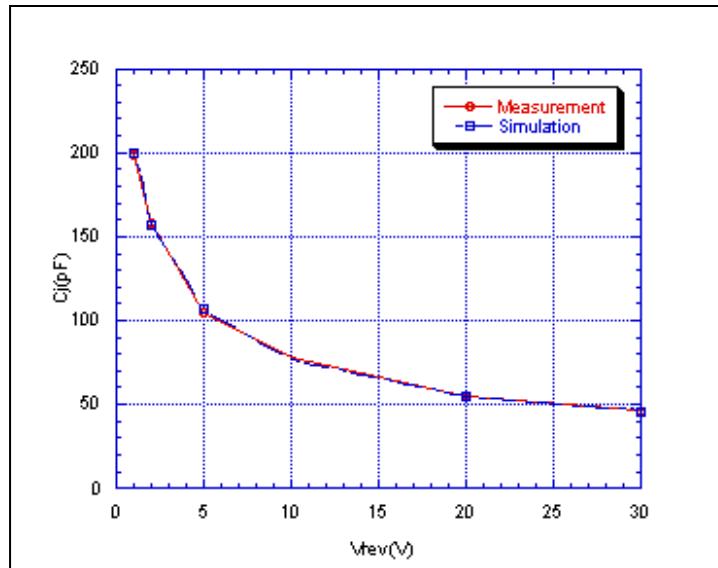


Evaluation Circuit



## Comparison Graph

### Circuit Simulation Result



### Simulation Result

$V_{rev}(V)$	$C_j(pF)$ Measurement	$C_j(pF)$ Simulation	%Error
1	198.000	200.000	1.01
2	158.000	157.300	-0.44
5	105.000	106.900	1.81
10	78.000	77.100	-1.15
20	54.500	54.700	0.37
30	45.100	45.000	-0.22